

Standard LDO Regulators

Standard Fixed Output LDO Regulators



BD80C0AFPS, BD90C0AFPS

No.10021EAT02

●Description

The BD80C0AFPS, BD90C0AFPS is low-saturation regulator. This IC has a built-in over-current protection circuit that prevents the destruction of the IC due to output short circuits and a thermal shutdown circuit that protects the IC from thermal damage due to overloading.

●Features

- 1) Output Current: 1A
- 2) Output Voltage: 8.0V / 9.0V
- 3) High Output Voltage Precision: $\pm 1\%$
- 4) Low saturation with PDMOS output
- 5) Built-in over-current protection circuit that prevents the destruction of the IC due to output short circuits
- 6) Built-in thermal shutdown circuit for protecting the IC from thermal damage due to overloading
- 7) Low ESR Capacitor
- 8) TO252S-3 packaging

●Applications

Audiovisual equipments, FPDs, televisions, personal computers or any other consumer device

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Supply Voltage ^{*1}	V _{CC}	-0.3 ~ +35.0	V
Power Dissipation ^{*2}	P _d	1.2	W
Operating Temperature Range	T _{opr}	-40 ~ +105	°C
Storage Temperature Range	T _{stg}	-55 ~ +150	°C
Maximum Junction Temperature	T _{jmax}	+150	°C

^{*1} Not to exceed P_d.

^{*2} TO252S-3: Reduced by 9.6mW / °C over Ta = 25°C, when mounted on glass epoxy board: 70mm × 70mm × 1.6mm.

NOTE: This product is not designed for protection against radioactive rays.

●Operating conditions (Ta=25°C)

■BD80C0AFPS

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V _{CC}	9.0	25.0	V
Output Current	I _o	0	1.0	A

■BD90C0AFPS

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V _{CC}	10.0	25.0	V
Output Current	I _o	0	1.0	A

●Electrical characteristics

■BD80C0AFPS

(Unless otherwise specified, Ta=25°C, Vcc=13V, Io=0mA)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Bias Current	Ib	—	0.6	1.0	mA	
Output Voltage	Vo	7.92	8.00	8.08	V	Io=500mA
Dropout Voltage	ΔV_d	—	0.3	0.5	V	$V_{CC}=V_o \times 0.95$, Io=500mA
Ripple Rejection	R.R.	40	50	—	dB	f=120Hz, $e_{in}^* = 1V_{rms}$, Io=100mA
Line Regulation	Reg.I	—	20	60	mV	$V_{CC}=9 \rightarrow 25V$
Load Regulation	Reg.L	—	$V_o \times 0.010$	$V_o \times 0.015$	V	Io=5mA \rightarrow 1A
Temperature Coefficient of Output Voltage	Tcvo.1	—	+0.04	—	%/°C	Io=5mA, Tj=-40 ~ -20°C
	Tcvo.2	—	± 0.005	—	%/°C	Io=5mA, Tj=-20 ~ +105°C

*1 e_{in} : Input Voltage Ripple

■BD90C0AFPS

(Unless otherwise specified, Ta=25°C, Vcc=14V, Io=0mA)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Bias Current	Ib	—	0.6	1.0	mA	
Output Voltage	Vo	8.91	9.00	9.09	V	Io=500mA
Dropout Voltage	ΔV_d	—	0.3	0.5	V	$V_{CC}=V_o \times 0.95$, Io=500mA
Ripple Rejection	R.R.	40	50	—	dB	f=120Hz, $e_{in}^* = 1V_{rms}$, Io=100mA
Line Regulation	Reg.I	—	20	60	mV	$V_{CC}=10 \rightarrow 25V$
Load Regulation	Reg.L	—	$V_o \times 0.010$	$V_o \times 0.015$	V	Io=5mA \rightarrow 1A
Temperature Coefficient of Output Voltage	Tcvo.1	—	+0.04	—	%/°C	Io=5mA, Tj=-40 ~ -20°C
	Tcvo.2	—	± 0.005	—	%/°C	Io=5mA, Tj=-20 ~ +105°C

*1 e_{in} : Input Voltage Ripple

●Electrical characteristic curves (Reference data)

BD80C0AFPS(Unless otherwise specified, $T_a=25^{\circ}\text{C}$, $V_{cc}=13\text{V}$, $I_o=0\text{mA}$)

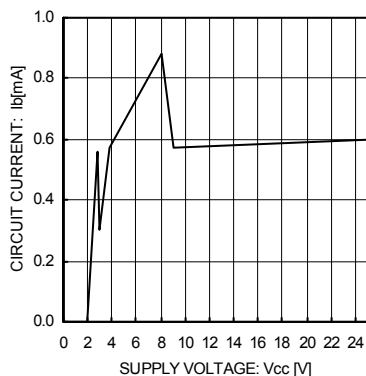


Fig.1 Circuit Current

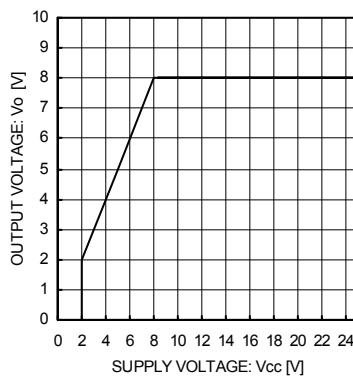


Fig.2 Line Regulation
($I_o=0\text{mA}$)

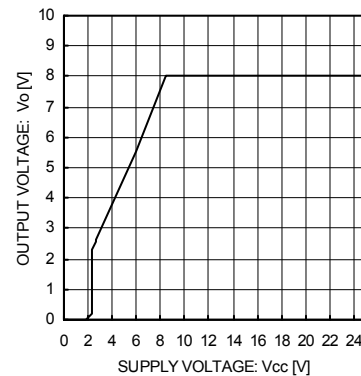


Fig.3 Line Regulation
($I_o=500\text{mA}$)

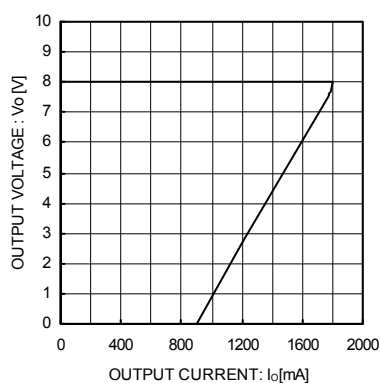


Fig.4 Load Regulation

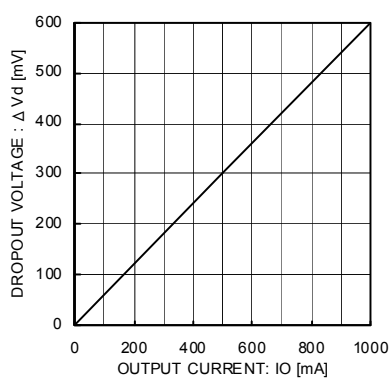


Fig.5 Dropout Voltage
($V_{cc}=V_o \times 0.95\text{V}$)
($I_o=0\text{mA} \rightarrow 1000\text{mA}$)

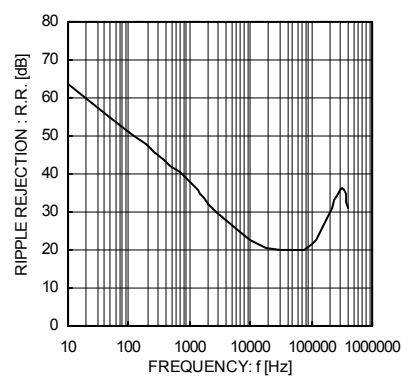


Fig.6 Ripple Rejection
($I_o=100\text{mA}$)

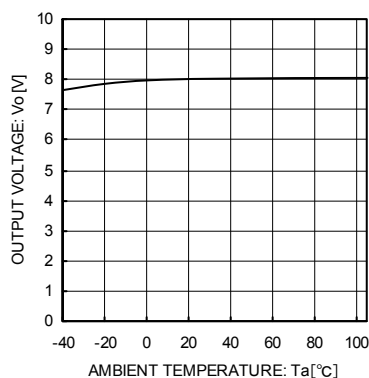


Fig.7 Output Voltage
Temperature Characteristics

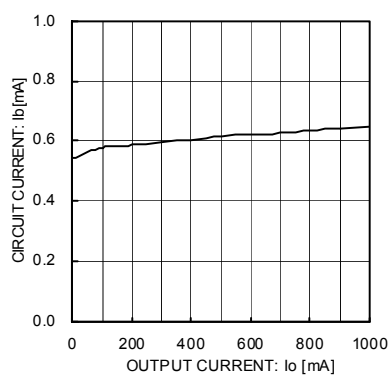


Fig.8 Circuit Current
($I_o=0\text{mA} \rightarrow 1000\text{mA}$)

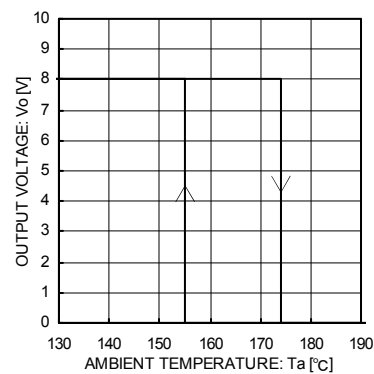


Fig.9 Thermal Shutdown
Circuit Characteristics

●Electrical characteristic curves (Reference data)

BD90C0AFPS (Unless otherwise specified, $T_a=25^{\circ}\text{C}$, $V_{cc}=14\text{V}$, $I_o=0\text{mA}$)

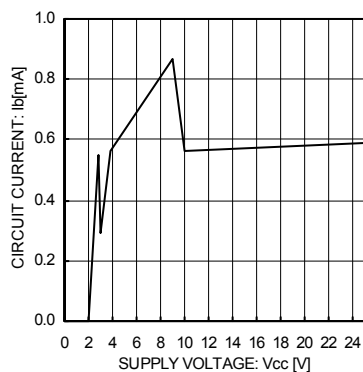


Fig.10 Circuit Current

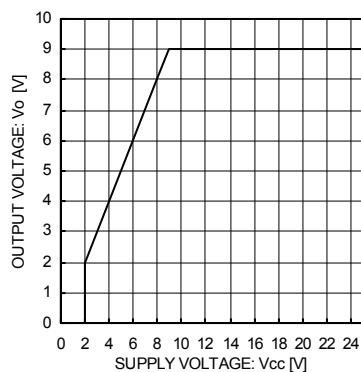


Fig.11 Line Regulation
($I_o=0\text{mA}$)

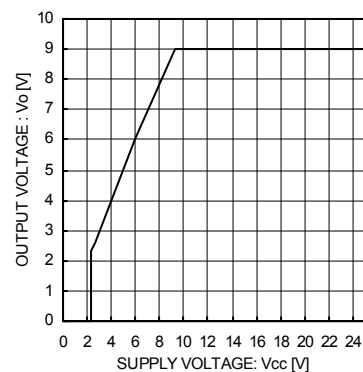


Fig.12 Line Regulation
($I_o=500\text{mA}$)

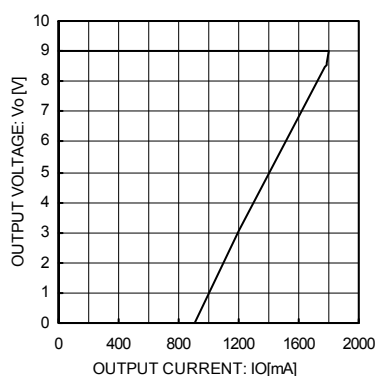


Fig.13 Load Regulation

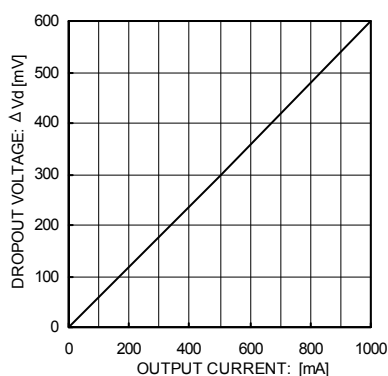


Fig.14 Dropout Voltage
($V_{cc}=V_o \times 0.95\text{V}$)
($I_o=0\text{mA} \rightarrow 1000\text{mA}$)

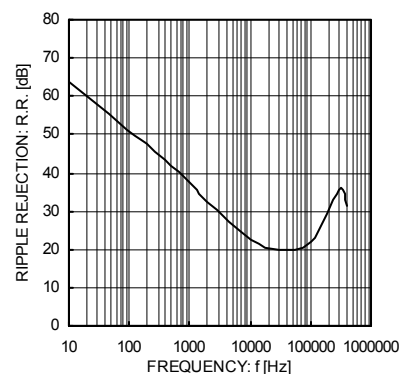


Fig.15 Ripple Rejection
($I_o=100\text{mA}$)

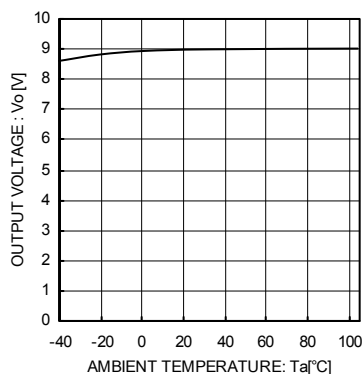


Fig.16 Output Voltage
Temperature Characteristics

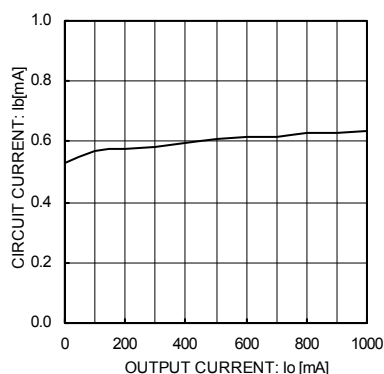


Fig.17 Circuit Current
($I_o=0\text{mA} \rightarrow 1000\text{mA}$)

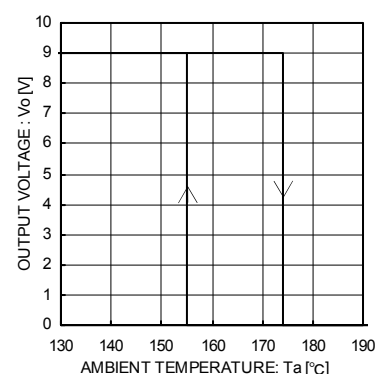
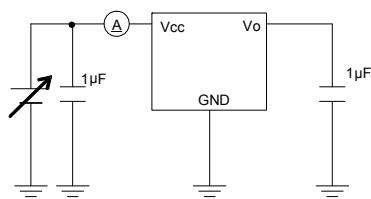
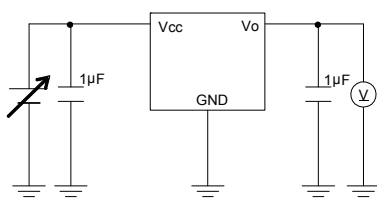


Fig.18 Thermal Shutdown
Circuit Characteristics

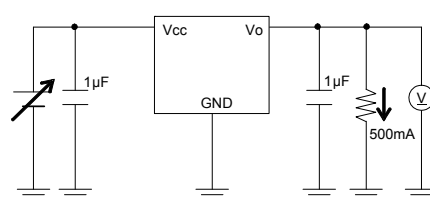
●BD80C0AFPS, BD90C0AFPS Measurement Circuit for Reference Data



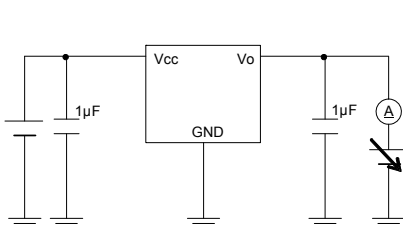
Measurement Circuit of Fig.1 and Fig.10



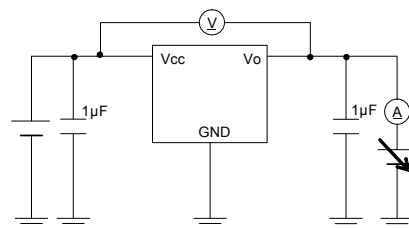
Measurement Circuit of Fig.2 and Fig.11



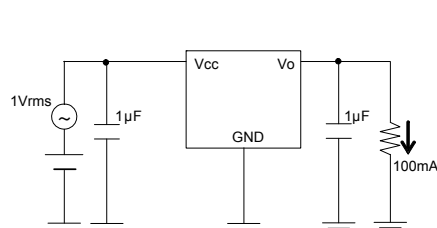
Measurement Circuit of Fig.3 and Fig.12



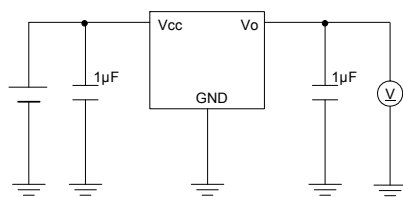
Measurement Circuit of Fig.4 and Fig.13



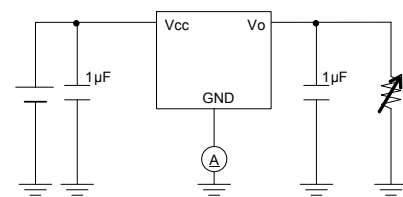
Measurement Circuit of Fig.5 and Fig.14



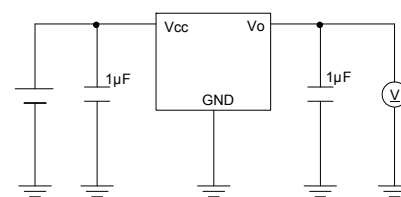
Measurement Circuit of Fig.6 and Fig.15



Measurement Circuit of Fig.7 and Fig.16



Measurement Circuit of Fig.8 and Fig.17



Measurement Circuit of Fig.9 and Fig.18

●BD80C0AFPS, BD90C0AFPS Block diagrams

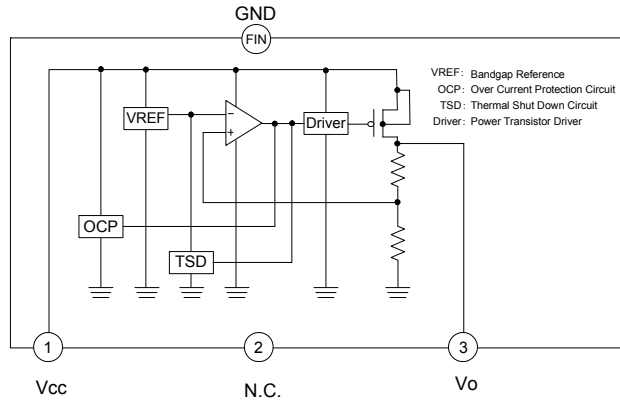
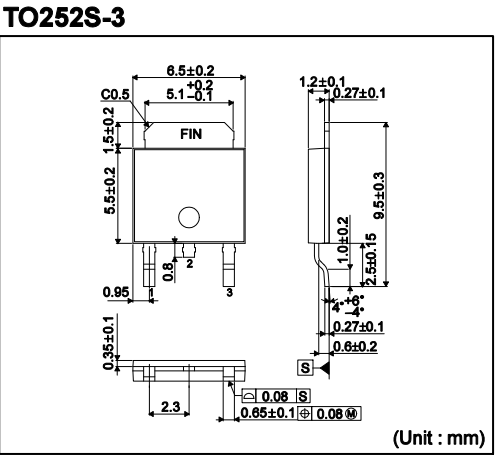


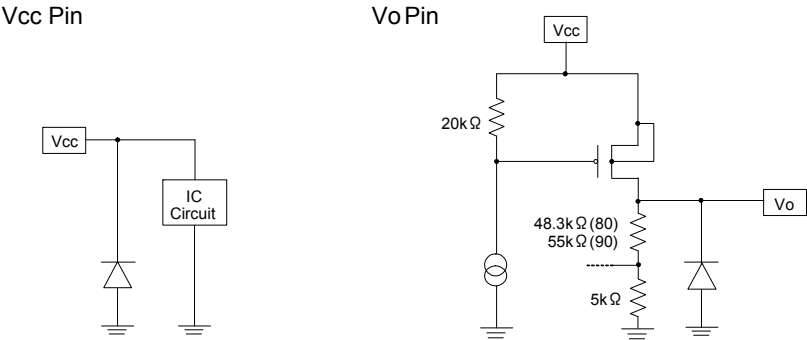
Fig.19

Pin No..	Pin Name	Function
1	Vcc	Power Supply Pin
2	N.C.	N.C. Pin
3	Vo	Output Pin
FIN	GND	GND

●Package dimensions



●Input / Output Equivalent Circuit Diagrams



Thermal Design

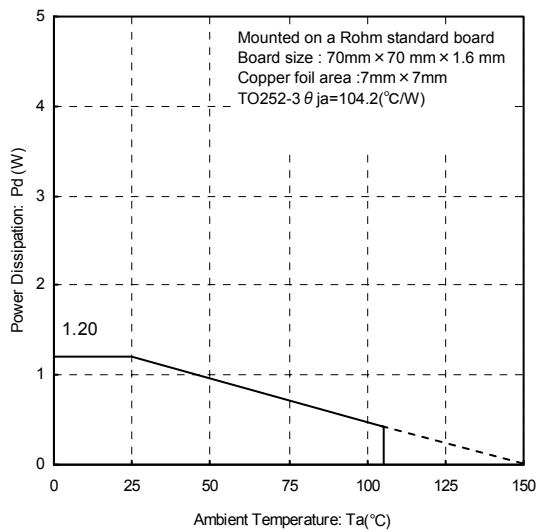


Fig.20

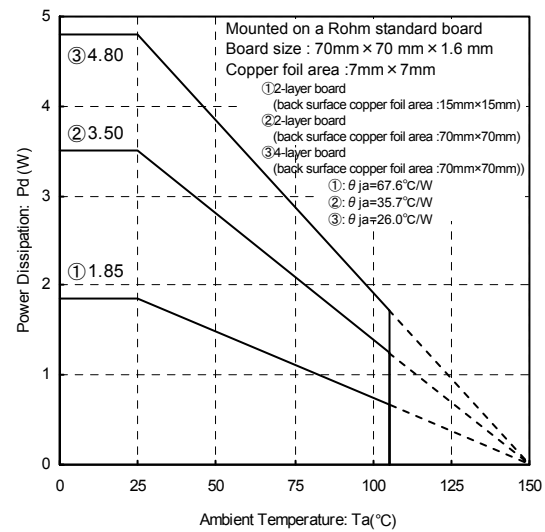


Fig.21(reference data)

When using at temperatures over $T_a=25^{\circ}\text{C}$, please refer to the heat reducing characteristics shown in Fig.20 and Fig.21. The IC characteristics are closely related to the temperature at which the IC is used, so it is necessary to operate the IC at temperatures less than the maximum junction temperature $T_{j\text{max}}$.

Fig.20 and Fig.21 shows the acceptable loss and heat reducing characteristics of the TO252S-3 package. Even when the ambient temperature T_a is a normal temperature (25°C), the chip (junction) temperature T_j may be quite high so please operate the IC at temperatures less than the acceptable loss P_d .

The calculation method for power consumption $P_c(\text{W})$ is as follows : (Fig.21③)

$$P_c = (V_{cc} - V_o) \times I_o + V_{cc} \times I_b$$

$$\text{Acceptable loss } P_d \geq P_c$$

Solving this for load current I_o in order to operate within the acceptable loss,

$$I_o \leq \frac{P_d - V_{cc} \times I_b}{V_{cc} - V_o}$$

(Please refer to Fig.8, Fig.17 for I_b .)

It is then possible to find the maximum load current $I_{o\text{Max}}$ with respect to the applied voltage V_{cc} at the time of thermal design.

Calculation Example for BD80C0AFPS)

When $T_a=85^{\circ}\text{C}$, $V_{cc}=13\text{V}$, $V_o=8\text{V}$

$$I_o \leq \frac{2.496 - 13 \times I_b}{5}$$

$$I_o \leq 497.6\text{mA} \quad (I_b: 0.6\text{mA})$$

$$\left[\begin{array}{l} \text{Fig.21③} : \theta_{ja}=26.0^{\circ}\text{C/W} \rightarrow -38.4\text{mW/}^{\circ}\text{C} \\ 25^{\circ}\text{C}=4.80\text{W} \rightarrow 85^{\circ}\text{C}=2.496\text{W} \end{array} \right]$$

V_{cc} : Input voltage
 V_o : Output voltage
 I_o : Load current
 I_b : Circuit current
 I_{short} : Short current

Please refer to the above information and keep thermal designs within the scope of acceptable loss for all operating temperature ranges. The power consumption P_c of the IC when there is a short circuit (short between V_o and GND) is :

$$P_c = V_{cc} \times (I_b + I_{\text{short}})$$

(Please refer to Fig.4, Fig.13 for I_{short} .)

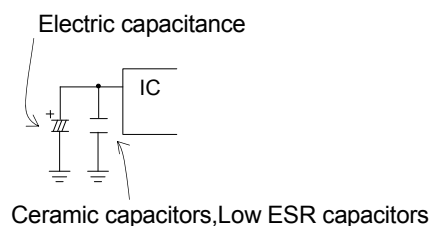
●Notes for use

1. Absolute maximum ratings
Use of the IC in excess of absolute maximum ratings (such as the input voltage or operating temperature range) may result in damage to the IC. Assumptions should not be made regarding the state of the IC (e.g., short mode or open mode) when such damage is suffered. If operational values are expected to exceed the maximum ratings for the device, consider adding protective circuitry (such as fuses) to eliminate the risk of damaging the IC.
2. Electrical characteristics described in these specifications may vary, depending on temperature, supply voltage external circuits and other conditions. Therefore, be sure to check all relevant factors, including transient characteristics.
3. GND potential
The potential of the GND pin must be the minimum potential in the system in all operating conditions. Ensure that no pins are at a voltage below the GND at any time, regardless of transient characteristics.
4. Ground wiring pattern
When using both small-signal and large-current GND traces, the two ground traces should be routed separately but connected to a single ground potential within the application in order to avoid variations in the small-signal ground caused by large currents. Also ensure that the GND traces of external components do not cause variations on GND voltage. The power supply and ground lines must be as short and thick as possible to reduce line impedance.
5. Inter-pin shorts and mounting errors
Use caution when orienting and positioning the IC for mounting on printed circuit boards. Improper mounting may result in damage to the IC. Shorts between output pins or between output pins and the power supply or GND pins (caused by poor soldering or foreign objects) may result in damage to the IC.
6. Operation in strong electromagnetic fields
Using this product in strong electromagnetic fields may cause IC malfunction. Caution should be exercised in applications where strong electromagnetic fields may be present.
7. Testing on application boards
When testing the IC on an application board, connecting a capacitor directly to a low-impedance pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from a jig or fixture during the evaluation process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.
8. Thermal consideration
Use a thermal design that allows for a sufficient margin in light of the P_d in actual operating conditions. Consider P_c that does not exceed P_d in actual operating conditions. ($P_d \geq P_c$)

$$\left[\begin{array}{l} T_{jmax}: \text{Maximum junction temperature}=150^{\circ}\text{C}, T_a: \text{Peripheral temperature}[^{\circ}\text{C}], \\ \theta_{ja}: \text{Thermal resistance of package-ambience}[^{\circ}\text{C}/\text{W}], P_d: \text{Package Power dissipation [W]} \end{array} \right]$$

P_c : Power dissipation [W], V_{cc} : Input Voltage, V_o : Output Voltage, I_o : Load, I_b : Bias Current

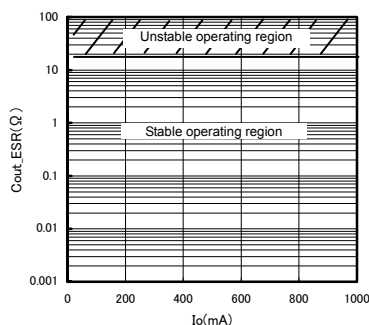
9. Vcc pin
Insert a capacitor (capacitor $\geq 1\mu\text{F} \sim$) between the Vcc and GND pins. The appropriate capacitance value varies by application. Be sure to allow a sufficient margin for input voltage levels.



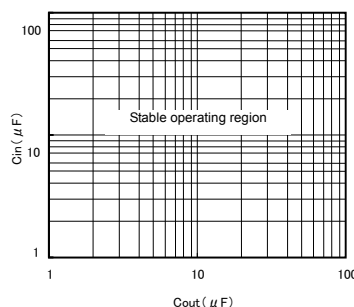
10. Output pins

It is necessary to place capacitors between each output pin and GND to prevent oscillation on the output. Usable capacitance values range from $1\mu\text{F}$ to $1000\mu\text{F}$. Ceramic capacitors can be used as long as their ESR value is low enough to prevent oscillation (0.001Ω to 20Ω). Abrupt fluctuations in input voltage and load conditions may affect the output voltage. Output capacitance values should be determined only through sufficient testing of the actual application.

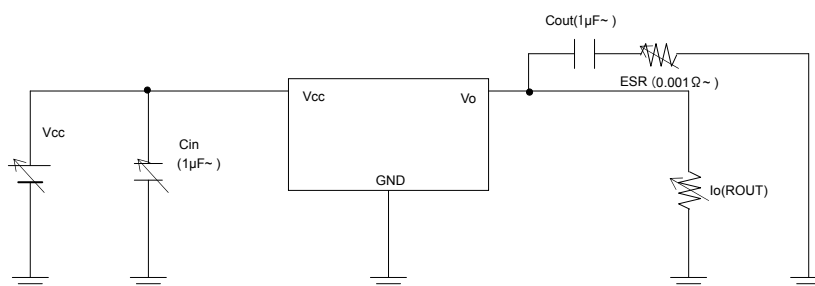
$V_{CC}=9\text{V}\sim 25\text{V}$ (BD80C0AFPS)
 $V_{CC}=10\text{V}\sim 25\text{V}$ (BD90C0AFPS)
 $T_a=-40^\circ\text{C}\sim +105^\circ\text{C}$
 $C_{in}=1\mu\text{F}\sim 100\mu\text{F}$ $C_{out}=1\mu\text{F}\sim 100\mu\text{F}$

Cout_ESR vs I_o (reference data)

$V_{CC}=9\text{V}\sim 25\text{V}$ (BD80C0AFPS)
 $V_{CC}=10\text{V}\sim 25\text{V}$ (BD90C0AFPS)
 $T_a=-40^\circ\text{C}\sim +105^\circ\text{C}$
 $C_{in}=1\mu\text{F}\sim 100\mu\text{F}$ $C_{out}=1\mu\text{F}\sim 100\mu\text{F}$
 $I_o=0\text{A}\sim 1\text{A}$



Cin vs Cout(reference data)



※Operation Notes10 Measurement circuit

11. For a steep change of the V_{CC} voltage

Because MOS for output Transistor is used when an input voltage change is very steep, it may evoke large current. When selecting the value of external circuit constants, please make sure that the operation on the actual application takes these conditions into account.

12. For an infinitesimal fluctuations of output voltage.

At the use of the application that infinitesimal fluctuations of output voltage caused by some factors (e.g. disturbance noise, input voltage fluctuations, load fluctuations, etc.), please take enough measures to avoid some influence (e.g. insert the filter, etc.).

13. Over current protection circuit (OCP)

The IC incorporates an integrated over-current protection circuit that operates in accordance with the rated output capacity. This circuit serves to protect the IC from damage when the load becomes shorted. It is also designed to limit output current (without latching) in the event of a large and instantaneous current flow from a large capacitor or other component. These protection circuits are effective in preventing damage due to sudden and unexpected accidents. However, the IC should not be used in applications characterized by the continuous or transitive operation of the protection circuits.

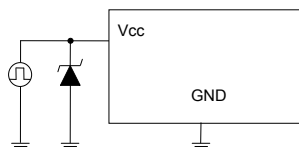
14. Thermal shutdown circuit (TSD)

The IC incorporates a built-in thermal shutdown circuit, which is designed to turn the IC off completely in the event of thermal overload. It is not designed to protect the IC from damage or guarantee its operation. ICs should not be used after this function has activated, or in applications where the operation of this circuit is assumed.

15. Applications or inspection processes where the potential of the V_{CC} pin or other pins may be reversed from their normal state may cause damage to the IC's internal circuitry or elements. Use an output pin capacitance of 1000μF or lower in case V_{CC} is shorted with the GND pin while the external capacitor is charged. Insert a diode in series with V_{CC} to prevent reverse current flow, or insert bypass diodes between V_{CC} and each pin.

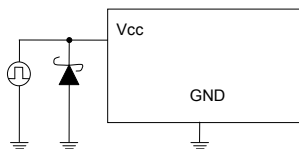
16. Positive voltage surges on V_{CC} pin

A power zener diode should be inserted between V_{CC} and GND for protection against voltage surges of more than 35V on the V_{CC} pin.



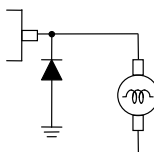
17. Negative voltage surges on V_{CC} pin

A schottky barrier diode should be inserted between V_{CC} and GND for protection against voltages lower than GND on the V_{CC} pin.



18. Output protection diode

Loads with large inductance components may cause reverse current flow during startup or shutdown. In such cases, a protection diode should be inserted on the output to protect the IC.



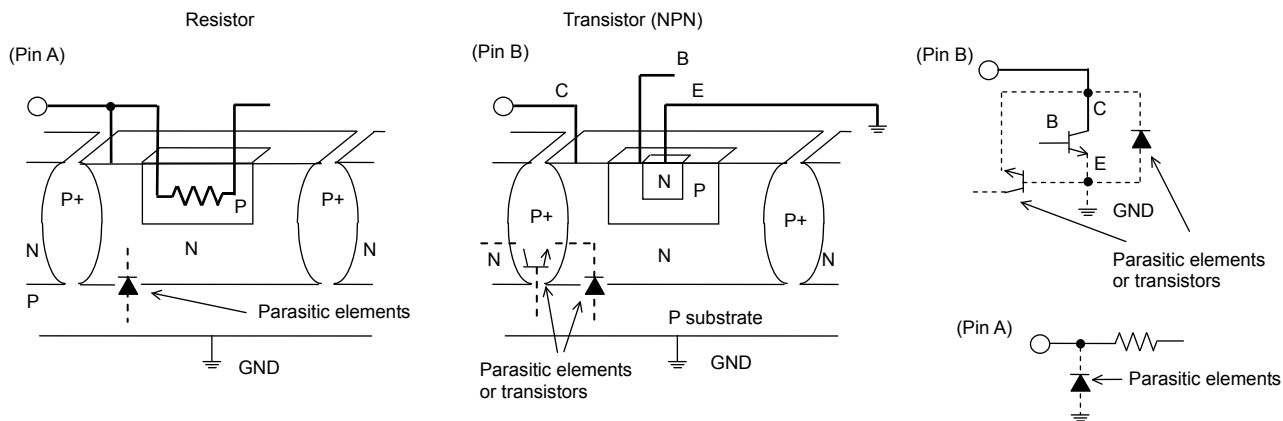
19. Regarding input pins of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. PN junctions are formed at the intersection of these P layers with the N layers of other elements, creating parasitic diodes and/or transistors. For example (refer to the figure below):

○When $GND > Pin A$ and $GND > Pin B$, the PN junction operates as a parasitic diode

○When $GND > Pin B$, the PN junction operates as a parasitic transistor

Parasitic diodes occur inevitably in the structure of the IC, and the operation of these parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Accordingly, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

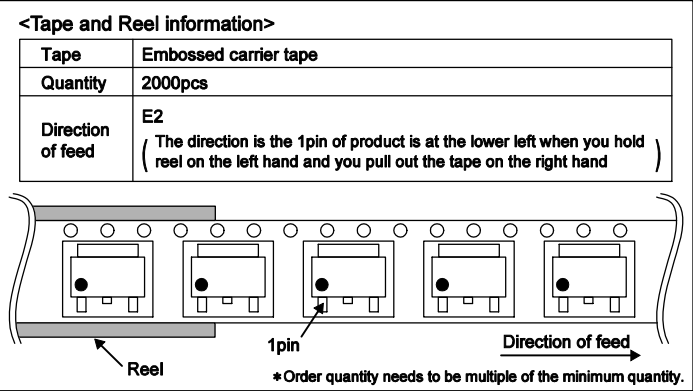
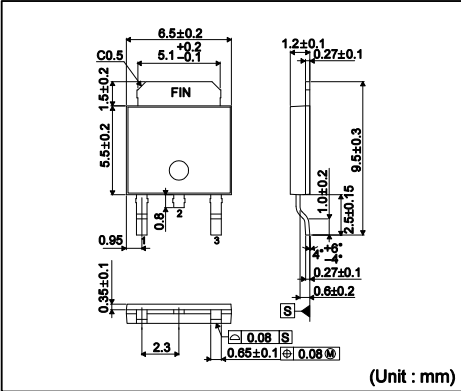


Example of Simple Monolithic IC Architecture

●Ordering part number

B	D	8	0	C	0	A	F	P	S	-	E	2
ROHM model Name		Output Voltage 80:8V Output 90:9V Output		Current capacity C0A:1A		Package FPS:TO252S-3		Packaging specification E2: Embossed tape and reel				

TO252S-3



Notes

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